

Product Summary

BV_{DSS}	$R_{DS(ON)}$ Max	I_D Max $T_C = +25^\circ C$
-30V	20m Ω @ $V_{GS} = -10V$	-30A
	29m Ω @ $V_{GS} = -5V$	-30A

Description and Applications

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

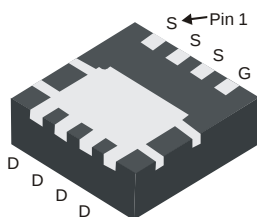
Features and Benefits

- Low $R_{DS(ON)}$ – ensures on state losses are minimized.
- Small form factor thermally efficient package enables higher density end products.
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product.
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

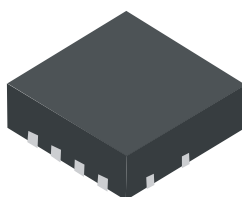
Mechanical Data

- Case: PowerDI[®] 3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208@3
- Weight: 0.03 grams (Approximate)

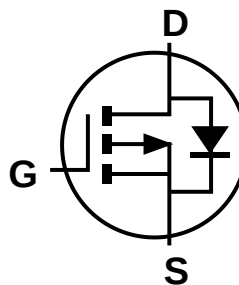
PowerDI3333-8



Bottom View



Top View



Equivalent Circuit

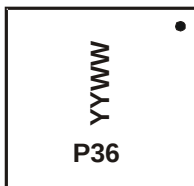
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3036SFG-7	PowerDI3333-8	2,000/Tape & Reel
DMP3036SFG-13	PowerDI3333-8	3,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

PowerDI3333-8



P36 = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 17 = 2017)
 WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	-30	V
Gate-Source Voltage		V _{GSS}	±25	V
Continuous Drain Current (Note 6) V _{GS} = -10V	T _A = +25°C	I _D	-8.7	A
	T _A = +70°C		-7.0	
Continuous Drain Current (Note 7) V _{GS} = -10V	T _C = +25°C	I _D	-30	A
	T _C = +70°C		-25	
Continuous Drain Current (Note 6) V _{GS} = -5V	T _A = +25°C	I _D	-7.2	A
	T _A = +70°C		-5.8	
Continuous Drain Current (Note 7) V _{GS} = -5V	T _C = +25°C	I _D	-30	A
	T _C = +70°C		-24	
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)		I _{DM}	-80	A
Maximum Continuous Body Diode Forward Current (Note 6)		I _S	-3.6	A
Avalanche Current (Note 7) L=0.3mH		I _{AS}	-17.5	A
Avalanche Energy (Note 7) L=0.3mH		E _{AS}	64	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P _D	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	137	°C/W
	t<10s		65	°C/W
Total Power Dissipation (Note 6)		P _D	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{θJA}	55	°C/W
	t<10s		26	°C/W
Thermal Resistance, Junction to Case (Note 7)		R _{θJC}	3.5	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30	-	-	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current	I _{DSS}	-	-	-1.0	μA	V _{DS} = -30V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	V _{GS} = ±25V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	-1.0	-2.0	-2.5	V	V _{DS} = V _{GS} , I _D = -250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	-	13	20	mΩ	V _{GS} = -10V, I _D = -8A
		-	18.4	29		V _{GS} = -5V, I _D = -5A
Diode Forward Voltage	V _{SD}	-	-0.7	-1.2	V	V _{GS} = 0V, I _S = -1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	-	1931	-	pF	V _{DS} = -15V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	-	226	-	pF	
Reverse Transfer Capacitance	C _{rss}	-	168	-	pF	
Gate Resistance	R _g	-	10.9	-	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge V _{GS} = -5V	Q _g	-	8.8	-	nC	V _{DS} = -15V, I _D = -10A
Total Gate Charge V _{GS} = -10V	Q _g	-	16.5	-	nC	
Gate-Source Charge	Q _{gs}	-	2.6	-	nC	
Gate-Drain Charge	Q _{gd}	-	3.6	-	nC	
Turn-On Delay Time	t _{D(ON)}	-	8.2	-	ns	V _{GS} = -10V, V _{DD} = -15V, R _{GEN} = 3Ω, I _D = -10A
Turn-On Rise Time	t _R	-	14	-	ns	
Turn-Off Delay Time	t _{D(OFF)}	-	65	-	ns	
Turn-Off Fall Time	t _F	-	31.6	-	ns	
Reverse Recovery Time	t _{RR}	-	9.3	-	ns	I _F = -8A, di/dt = 500A/μs
Reverse Recovery Charge	Q _{RR}	-	12.2	-	nC	

- Notes:
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to product testing.

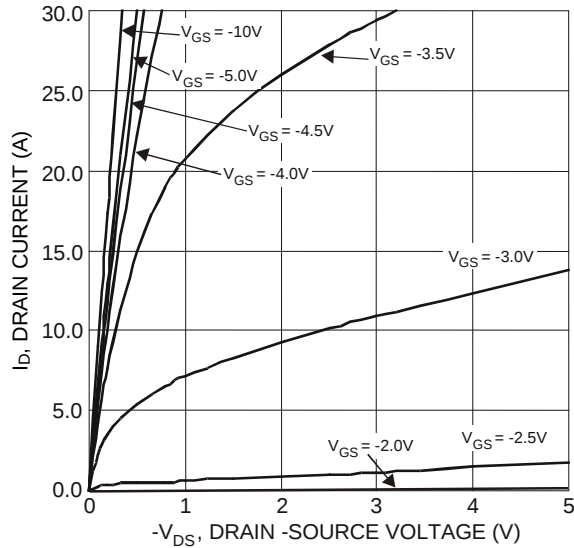


Figure 1 Typical Output Characteristics

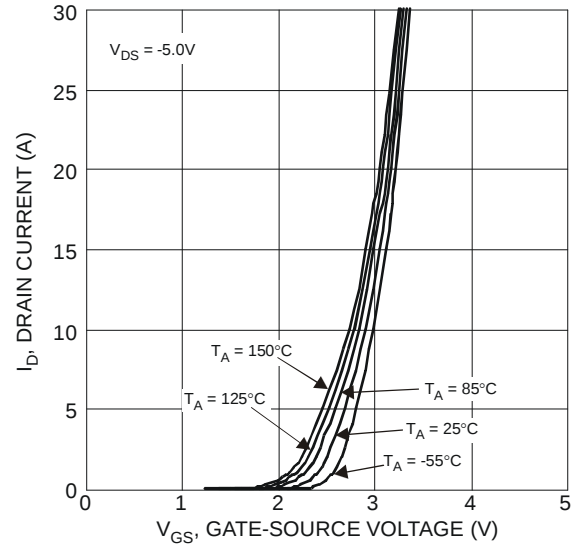


Figure 2 Typical Transfer Characteristics

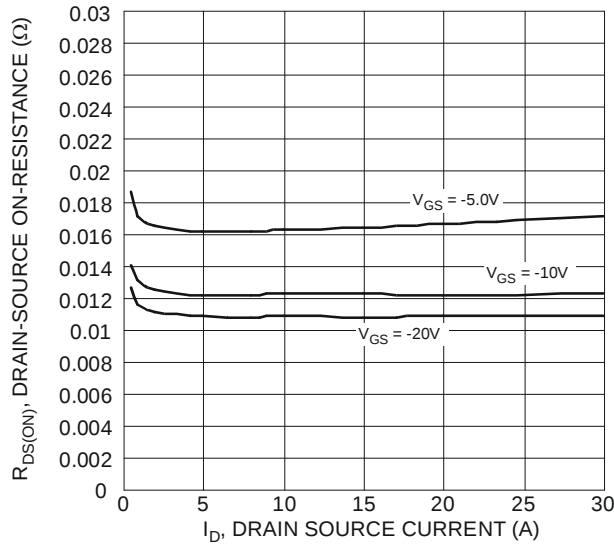


Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage

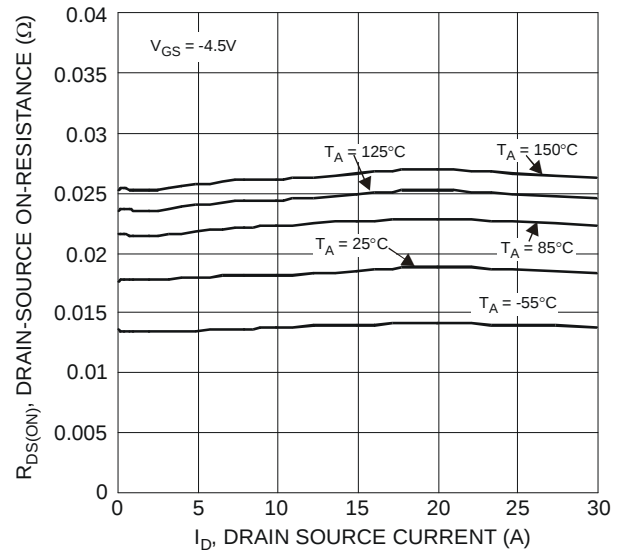


Figure 4 Typical On-Resistance vs. Drain Current and Temperature

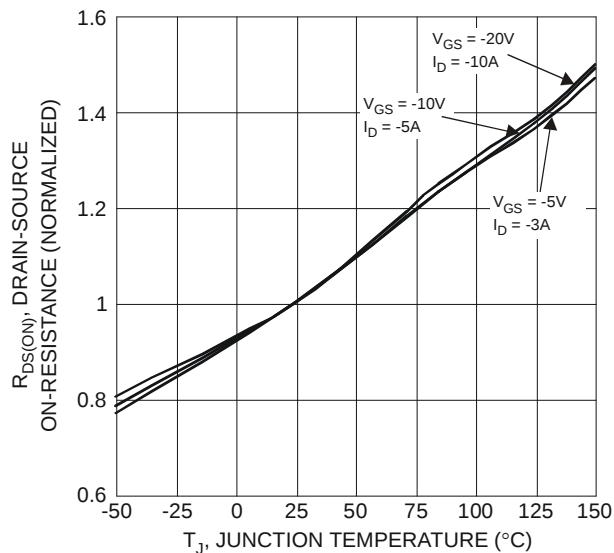


Figure 5 On-Resistance Variation with Temperature

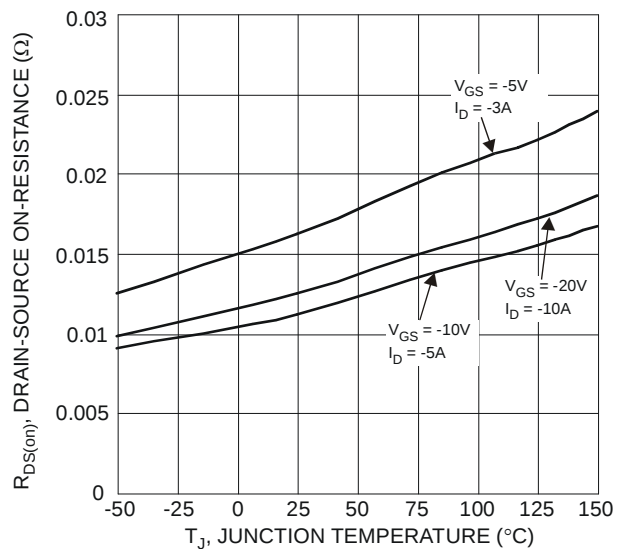


Figure 6 On-Resistance Variation with Temperature

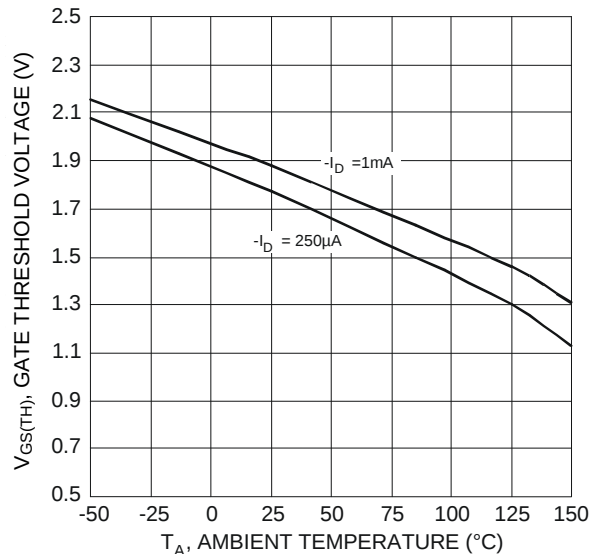


Figure 7 Gate Threshold Variation vs. Ambient Temperature

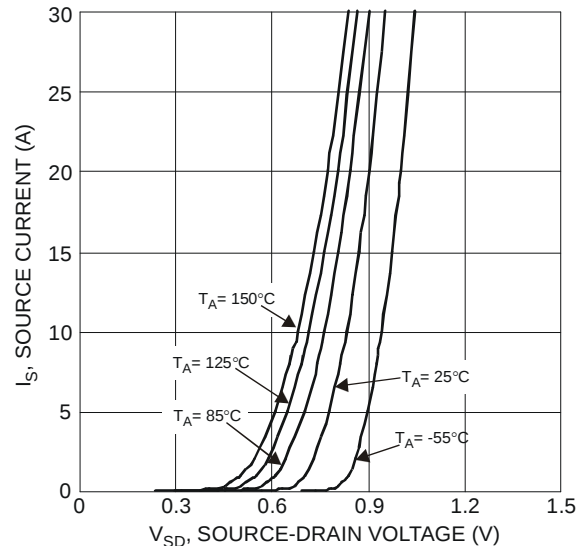


Figure 8 Diode Forward Voltage vs. Current

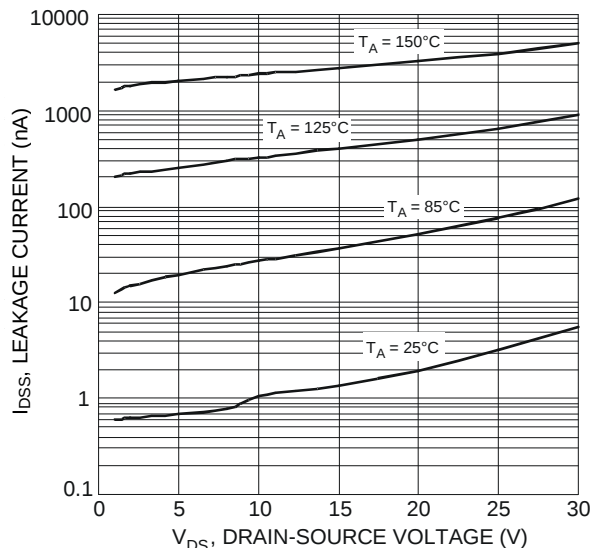


Figure 9 Typical Drain-Source Leakage Current vs. Voltage

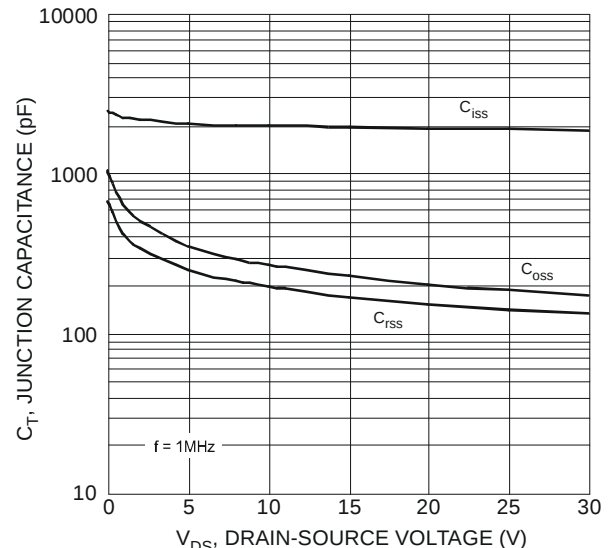


Figure 10 Typical Junction Capacitance

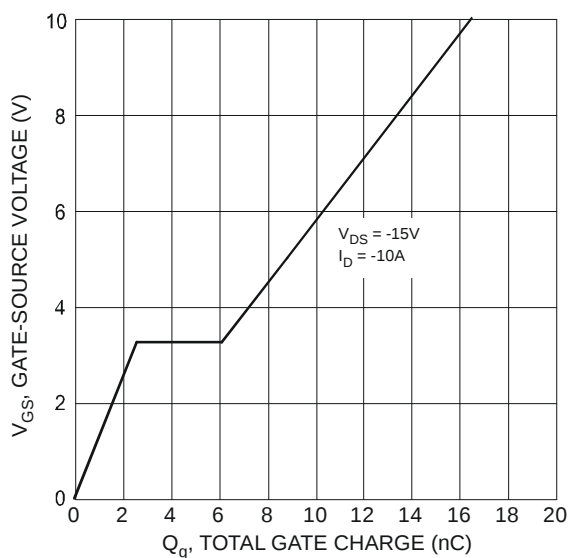


Figure 11 Gate-Charge Characteristics

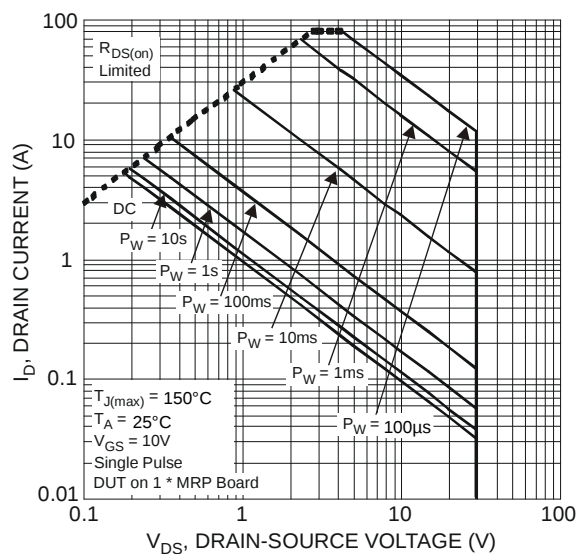


Figure 12 SOA, Safe Operation Area

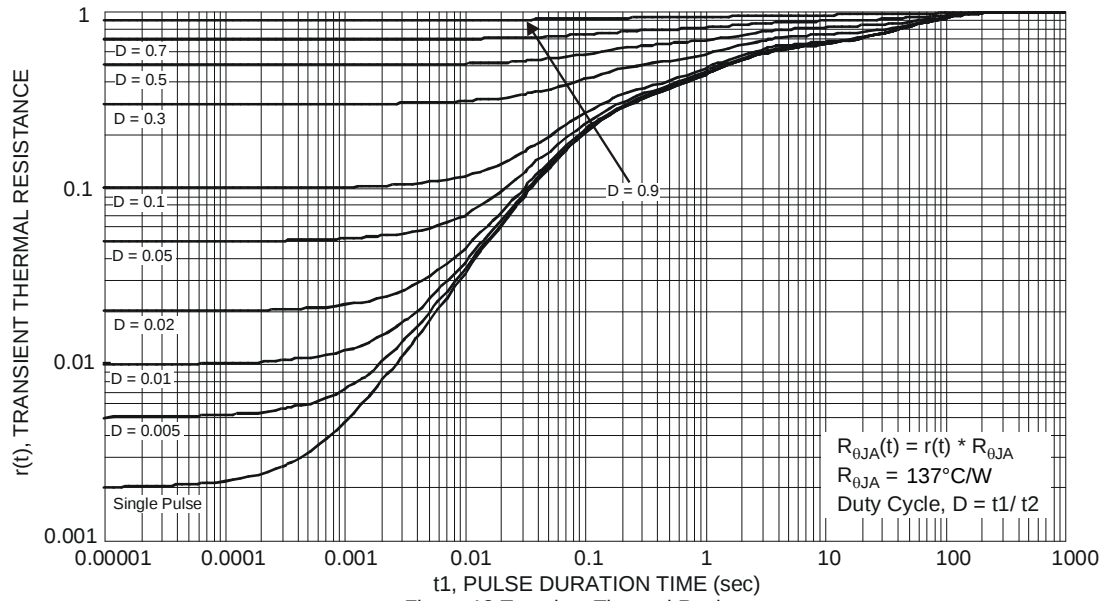
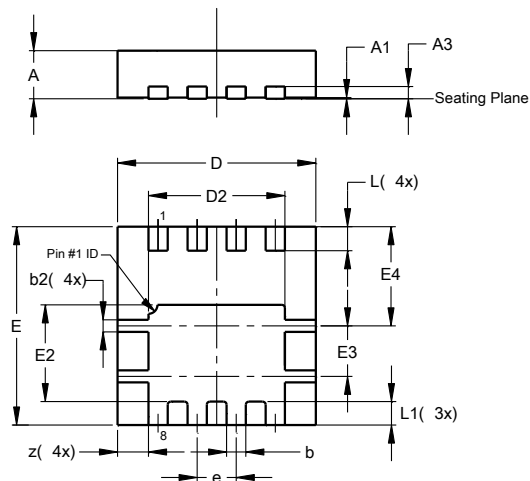


Figure 13 Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

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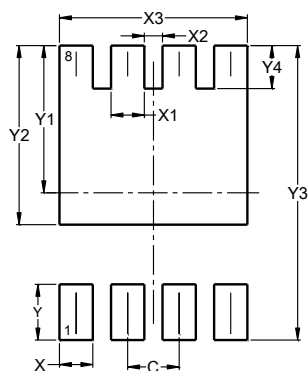


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Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	0.02
A3	—	—	0.20(3)
b	0.27	0.37	0.32
b2	0.15	0.25	0.20
D	3.25	3.35	3.30
D2	2.22	2.32	2.27
E	3.25	3.35	3.30
E2	1.56	1.66	1.61
E3	0.79	0.89	0.84
E4	1.60	1.70	1.65
e	—	—	0.65
L	0.35	0.45	0.40
L1	—	—	0.39
z	—	—	0.515
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

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Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540

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